SN74LVC2G66
INSTRUMENTS
www.ti.com

## FEATURES

- Available in the Texas Instruments NanoStar ${ }^{\text {TM }}$ and NanoFree ${ }^{\text {TM }}$ Packages
- 1.65-V to $5.5-\mathrm{V} \mathrm{V}_{\mathrm{CC}}$ Operation
- Inputs Accept Voltages to 5.5 V
- Max $t_{\text {pd }}$ of 0.8 ns at 3.3 V
- High On-Off Output Voltage Ratio
- High Degree of Linearity
- High Speed, Typically 0.5 ns
$\left(\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}\right.$ )
- Rail-to-Rail Input/Output
- Low On-State Resistance, Typically $\approx 6 \Omega$ ( $\mathrm{V}_{\mathrm{cc}}=4.5 \mathrm{~V}$ )
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

DCT OR DCU PACKAGE
(TOP VIEW)


YEA, YEP, YZA, OR YZP PACKAGE (BOTTOM VIEW)

| GND | O4 50 | 2A |
| :---: | :---: | :---: |
| 2 C | 0360 | 2B |
| 1B | O2 70 | 1C |
| 1A | 0180 | $\mathrm{V}_{\mathrm{CC}}$ |

## DESCRIPTION/ORDERING INFORMATION

This dual bilateral analog switch is designed for $1.65-\mathrm{V}$ to $5.5-\mathrm{V} \mathrm{V}_{\mathrm{CC}}$ operation.
The SN74LVC2G66 can handle both analog and digital signals. The device permits signals with amplitudes of up to 5.5 V (peak) to be transmitted in either direction.
NanoStar ${ }^{T M}$ and NanoFree ${ }^{\text {TM }}$ package technology is a major breakthrough in IC packaging concepts, using the die as the package.
Each switch section has its own enable-input control (C). A high-level voltage applied to C turns on the associated switch section.
Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

ORDERING INFORMATION

| TA | PACKAGE ${ }^{(1)}$ |  | ORDERABLE PART NUMBER | TOP-SIDE MARKING ${ }^{(2)}$ |
| :---: | :---: | :---: | :---: | :---: |
| $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ | NanoStar ${ }^{\text {TM }}$ - WCSP (DSBGA) <br> 0.17-mm Small Bump - YEA | Reel of 3000 | SN74LVC2G66YEAR | - -__C6 |
|  | NanoFree ${ }^{\text {TM }}$ - WCSP (DSBGA) <br> $0.17-\mathrm{mm}$ Small Bump - YZA (Pb-free) |  | SN74LVC2G66YZAR |  |
|  | NanoStar ${ }^{\text {TM }}$ - WCSP (DSBGA) 0.23-mm Large Bump - YEP |  | SN74LVC2G66YEPR |  |
|  | NanoFree ${ }^{\text {TM }}$ - WCSP (DSBGA) $0.23-\mathrm{mm}$ Large Bump - YZP (Pb-free) |  | SN74LVC2G66YZPR |  |
|  | SSOP - DCT | Reel of 3000 | SN74LVC2G66DCTR | C66_-_ |
|  | VSSOP - DCU | Reel of 3000 | SN74LVC2G66DCUR | C66 |
|  |  | Reel of 250 | SN74LVC2G66DCUT |  |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
(2) DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. DCU: The actual top-side marking has one additional character that designates the assembly/test site.
YEA/YZA, YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition ( $1=\mathrm{SnPb}, \bullet=\mathrm{Pb}-\mathrm{free}$ ).

[^0]FUNCTION TABLE
(EACH SECTION)

| CONTROL <br> INPUT <br> (C) | SWITCH |
| :---: | :---: |
| L | Off |
| H | On |

## LOGIC DIAGRAM, EACH SWITCH (POSITIVE LOGIC)



One of Two Switches

Absolute Maximum Ratings ${ }^{(1)}$
over operating free-air temperature range (unless otherwise noted)

|  |  |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {cc }}$ | Supply voltage range ${ }^{(2)}$ |  | -0.5 | 6.5 | V |
| $\mathrm{V}_{1}$ | Input voltage range ${ }^{(2)(3)}$ |  | -0.5 | 6.5 | V |
| $\mathrm{V}_{\mathrm{O}}$ | Switch I/O voltage range ${ }^{(2)(3)(4)}$ |  | -0.5 | $\mathrm{V}_{C C}+0.5$ | V |
|  | Control input clamp current | $V_{1}<0$ |  | -50 | mA |
| $\mathrm{I}_{\text {/OK }}$ | I/O port diode current | $\mathrm{V}_{1 / \mathrm{O}}<0$ or $\mathrm{V}_{\text {IO }}>\mathrm{V}_{\mathrm{CC}}$ |  | -50 | mA |
| $\mathrm{I}_{\mathrm{T}}$ | On-state switch current | $\mathrm{V}_{1 / \mathrm{O}}=0$ to $\mathrm{V}_{\mathrm{CC}}$ |  | $\pm 50$ | mA |
| Continuous current through V $\mathrm{CC}^{\text {or }}$ ord |  |  |  | $\pm 100$ | mA |
| $\theta_{\text {JA }}$ | Package thermal impedance ${ }^{(5)}$ | DCT package |  | 220 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | DCU package |  | 227 |  |
|  |  | YEA/YZA package |  | 140 |  |
|  |  | YEP/YZP package |  | 102 |  |
| $\mathrm{T}_{\text {stg }}$ Storage temperature range |  |  | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to ground, unless otherwise specified.
(3) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(4) This value is limited to 5.5 V maximum.
(5) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions ${ }^{(1)}$

|  |  |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage |  | 1.65 | 5.5 | V |
| $\mathrm{V}_{1 / \mathrm{O}}$ | I/O port voltage |  | 0 | $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-level input voltage, control input | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | $\mathrm{V}_{\mathrm{CC}} \times 0.65$ |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | $\times 0.7$ |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | $\mathrm{V}_{C C} \times 0.7$ |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | $\mathrm{V}_{\mathrm{CC}} \times 0.7$ |  |  |
| $\mathrm{V}_{\text {IL }}$ | Low-level input voltage, control input | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | $V_{C C} \times 0.35$ |  | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | $V_{C C} \times 0.3$ |  |  |
|  |  | $\mathrm{V}_{C C}=3 \mathrm{~V}$ to 3.6 V | $\mathrm{V}_{C C} \times 0.3$ |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | $\mathrm{V}_{C C} \times 0.3$ |  |  |
| $\mathrm{V}_{1}$ | Control input voltage |  |  | 5.5 | V |
| $\Delta t / \Delta v$ | Input transition rise/fall time | $\mathrm{V}_{\text {CC }}=1.65 \mathrm{~V}$ to 1.95 V |  | 20 | ns/V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V |  | 20 |  |
|  |  | $\mathrm{V}_{C C}=3 \mathrm{~V}$ to 3.6 V |  | 10 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V |  | 10 |  |
| $\mathrm{T}_{\text {A }}$ | Operating free-air temperature |  | -40 | 85 | ${ }^{\circ} \mathrm{C}$ |

(1) All unused inputs of the device must be held at $\mathrm{V}_{\mathrm{CC}}$ or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004. DUAL BILATERAL ANALOG SWITCH

## Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

(1) $T_{A}=25^{\circ} \mathrm{C}$

## Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 5)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $\begin{gathered} V_{\mathrm{cc}}=1.8 \mathrm{~V} \\ \pm 0.15 \mathrm{~V} \end{gathered}$ |  | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V} \\ \pm 0.2 \mathrm{~V} \end{gathered}$ |  | $\begin{gathered} \mathrm{V}_{\mathrm{Cc}}=3.3 \mathrm{~V} \\ \pm 0.3 \mathrm{~V} \end{gathered}$ |  | $\begin{gathered} \mathrm{V}_{\mathrm{cc}}=5 \mathrm{~V} \\ \pm 0.5 \mathrm{~V} \end{gathered}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX |  |
| $\mathrm{t}_{\mathrm{pd}}{ }^{(1)}$ | A or B | B or A |  | 2 |  | 1.2 |  | 0.8 |  | 0.6 | ns |
| $\mathrm{t}_{\text {en }}{ }^{(2)}$ | C | A or B | 2.3 | 10 | 1.6 | 5.6 | 1.5 | 4.4 | 1.3 | 3.9 | ns |
| $\mathrm{t}_{\text {dis }}{ }^{(3)}$ | C | A or B | 2.5 | 10.5 | 1.2 | 6.9 | 2 | 7.2 | 1.1 | 6.3 | ns |

(1) $t_{P L H}$ and $t_{P H L}$ are the same as $t_{\text {pd }}$. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
(2) $t_{\text {PZL }}$ and $t_{\text {PZH }}$ are the same as $t_{e n}$.
(3) $t_{\text {PLZ }}$ and $t_{\text {PHZ }}$ are the same as $t_{\text {dis }}$.

SN74LVC2G66
DUAL BILATERAL ANALOG SWITCH
SCES325H-JULY 2001-REVISED JULY 2005

## Analog Switch Characteristics

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| PARAMETER | $\begin{aligned} & \text { FROM } \\ & \text { (INPUT) } \end{aligned}$ | $\begin{gathered} \text { TO } \\ \text { (OUTPUT) } \end{gathered}$ | TEST CONDITIONS | $\mathrm{V}_{\mathrm{cc}}$ | TYP | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Frequency response (switch on) | A or B | $B$ or A | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{f}_{\mathrm{in}}=\text { sine wave } \\ & \text { (see Figure } 6 \text { ) } \end{aligned}$ | 1.65 V | 35 | MHz |
|  |  |  |  | 2.3 V | 120 |  |
|  |  |  |  | 3 V | 175 |  |
|  |  |  |  | 4.5 V | 195 |  |
|  |  |  | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}_{\mathrm{in}}=\text { sine wave } \\ & \text { (see Figure } 6 \text { ) } \end{aligned}$ | 1.65 V | >300 |  |
|  |  |  |  | 2.3 V | >300 |  |
|  |  |  |  | 3 V | >300 |  |
|  |  |  |  | 4.5 V | >300 |  |
| Crosstalk ${ }^{(1)}$(between switches) | A or B | $B$ or $A$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{f}_{\mathrm{in}}=1 \mathrm{MHz} \text {, (sine wave) } \\ & \text { (see Figure } 7 \text { ) } \end{aligned}$ | 1.65 V | -58 | dB |
|  |  |  |  | 2.3 V | -58 |  |
|  |  |  |  | 3 V | -58 |  |
|  |  |  |  | 4.5 V | -58 |  |
|  |  |  | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}_{\text {in }}=1 \mathrm{MHz} \text { (sine wave) } \\ & \text { (see Figure } 7 \text { ) } \end{aligned}$ | 1.65 V | -42 |  |
|  |  |  |  | 2.3 V | -42 |  |
|  |  |  |  | 3 V | -42 |  |
|  |  |  |  | 4.5 V | -42 |  |
| Crosstalk (control input to signal output) | C | A or B | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{f}_{\text {in }}=1 \mathrm{MHz} \text { (square wave) } \\ & \text { (see Figure } 8 \text { ) } \end{aligned}$ | 1.65 V | 35 | mV |
|  |  |  |  | 2.3 V | 50 |  |
|  |  |  |  | 3 V | 70 |  |
|  |  |  |  | 4.5 V | 100 |  |
| Feedthrough attenuation (switch off) | A or B | $B$ or $A$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{f}_{\mathrm{in}}=1 \mathrm{MHz} \text { (sine wave) } \\ & \text { (see Figure } \text { ) } \end{aligned}$ | 1.65 V | -58 | dB |
|  |  |  |  | 2.3 V | -58 |  |
|  |  |  |  | 3 V | -58 |  |
|  |  |  |  | 4.5 V | -58 |  |
|  |  |  | $\begin{aligned} & C_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}_{\text {in }}=1 \mathrm{MHz} \text { (sine wave) } \\ & \text { (see Figure } 9 \text { ) } \end{aligned}$ | 1.65 V | -42 |  |
|  |  |  |  | 2.3 V | -42 |  |
|  |  |  |  | 3 V | -42 |  |
|  |  |  |  | 4.5 V | -42 |  |
| Sine-wave distortion | $A$ or B | B or A | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \\ & \mathrm{f}_{\mathrm{in}}=1 \mathrm{kHz} \text { (sine wave) } \\ & \text { (see Figure 10) } \end{aligned}$ | 1.65 V | 0.1 | \% |
|  |  |  |  | 2.3 V | 0.025 |  |
|  |  |  |  | 3 V | 0.015 |  |
|  |  |  |  | 4.5 V | 0.01 |  |
|  |  |  | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \\ & \mathrm{f}_{\mathrm{in}}=10 \mathrm{kHz} \text { (sine wave) } \\ & \text { (see Figure 10) } \end{aligned}$ | 1.65 V | 0.15 |  |
|  |  |  |  | 2.3 V | 0.025 |  |
|  |  |  |  | 3 V | 0.015 |  |
|  |  |  |  | 4.5 V | 0.01 |  |

(1) Adjust $\mathrm{f}_{\text {in }}$ voltage to obtain 0 dBm at input.

## Operating Characteristics

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| PARAMETER |  | TEST CONDITIONS | $\mathrm{V}_{\mathrm{CC}}=1.8 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | TYP | TYP | TYP | TYP |  |
| $\mathrm{C}_{\mathrm{pd}}$ | Power dissipation capacitance |  | $\mathrm{f}=10 \mathrm{MHz}$ | 8 | 9 | 9.5 | 11 | pF |

PARAMETER MEASUREMENT INFORMATION


Figure 1. On-State Resistance Test Circuit


Figure 2. Typical $r_{\text {on }}$ as a Function of Input Voltage $\left(V_{1}\right)$ for $V_{1}=0$ to $V_{c c}$

## PARAMETER MEASUREMENT INFORMATION



Figure 3. Off-State Switch Leakage-Current Test Circuit


Figure 4. On-State Leakage-Current Test Circuit

## PARAMETER MEASUREMENT INFORMATION



NOTES: A. $C_{L}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega$.
D. The outputs are measured one at a time, with one transition per measurement.
E. $t_{P L Z}$ and $t_{P H Z}$ are the same as $t_{\text {dis }}$.
F. $t_{P Z L}$ and $t_{P Z H}$ are the same as $t_{\text {en }}$.
G. $t_{P L H}$ and $t_{P H L}$ are the same as $t_{p d}$.
H. All parameters and waveforms are not applicable to all devices.

Figure 5. Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION


Figure 6. Frequency Response (Switch On)


Figure 7. Crosstalk (Between Switches)

PARAMETER MEASUREMENT INFORMATION


Figure 8. Crosstalk (Control Input, Switch Output)


Figure 9. Feedthrough (Switch Off)

## PARAMETER MEASUREMENT INFORMATION



Figure 10. Sine-Wave Distortion

## PACKAGING INFORMATION

| Orderable Device | Status ${ }^{(1)}$ | Package <br> Type | Package <br> Drawing | Pins Package <br> Qty | Eco Plan ${ }^{(2)}$ | Lead/Ball Finish | MSL Peak Temp ${ }^{(3)}$ |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN74LVC2G66DCTR | ACTIVE | SM8 | DCT | 8 | 3000 | Pb-Free <br> (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC2G66DCTRE4 | ACTIVE | SM8 | DCT | 8 | 3000 | Pb-Free <br> (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC2G66DCUR | ACTIVE | US8 | DCU | 8 | 3000 | Pb-Free <br> (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC2G66DCURE4 | ACTIVE | US8 | DCU | 8 | 3000 | Pb-Free <br> (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC2G66DCUT | ACTIVE | US8 | DCU | 8 | 250 | Pb-Free <br> (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC2G66DCUTE4 | ACTIVE | US8 | DCU | 8 | 250 | Pb-Free <br> (RoHS) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC2G66YEAR | ACTIVE | WCSP | YEA | 8 | 3000 | TBD | SNPB | Level-1-260C-UNLIM |
| SN74LVC2G66YEPR | ACTIVE | WCSP | YEP | 8 | 3000 | TBD | SNPB | Level-1-260C-UNLIM |
| SN74LVC2G66YZAR | ACTIVE | WCSP | YZA | 8 | 3000 | Pb-Free <br> (RoHS) | SNAGCU | Level-1-260C-UNLIM |
| SN74LVC2G66YZPR | ACTIVE | WCSP | YZP | 8 | 3000 | Pb-Free <br> (RoHS) | SNAGCU | Level-1-260C-UNLIM |

${ }^{(1)}$ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.
${ }^{(2)}$ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS \& no $\mathrm{Sb} / \mathrm{Br}$ ) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed $0.1 \%$ by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb -Free products are suitable for use in specified lead-free processes.
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${ }^{(3)}$ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion
D. Falls within JEDEC MO-187 variation DA.

DCU (R-PDSO-G8)


NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Falls within JEDEC MO-187 variation CA.

YEA (R-XBGA-N8)


NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. NanoStar ${ }^{T M}$ package configuration.
D. Package complies to JEDEC MO-211 variation EB.
E. This package is tin-lead (SnPb). Refer to the 8 YZA package (drawing 4204151) for lead-free.

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INSTRUMENTS

YZA (R-XBGA-N8)


NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. NanoFree ${ }^{T M}$ package configuration.
D. Package complies to JEDEC MO-211 variation EB.
E. This package is lead-free. Refer to the 8 YEA package (drawing 4203167) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.

YZP (R-XBGA-N8)


NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. NanoFree ${ }^{\text {TM }}$ package configuration.
D. This package is lead-free. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

YEP (R-XBGA-N8)


NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. NanoStar ${ }^{T M}$ package configuration.
D. This package is tin-lead $(\mathrm{SnPb})$. Refer to the 8 YZP package (drawing 4204741) for lead-free.

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